### SONY

# 2SK613

Unit: mm

## Silfe 2016 M3 Ch 供应額 Junction FET 7-29-25

Package Outline

Description

Making the best of Epitaxy and Pattern latest technology, 2SK613 accomplishes so far unattainable levels of performance.

Usage with head amplifiers for video cameras and the like, ensures the highest efficiency.

#### **Features**

High figure of merit

High forward transfer admittance

$$\left( \begin{array}{l} V_{DS} = 5 \ V \\ V_{GS} = 0 \ V \end{array} \right) \ | \ Y_{fs} \ | \qquad 30 \ mS (Typ.)$$

Low input capacitance
 Ciss

Structure
Silicon N-Channel junction FET

#### Absolute Maximum Ratings (Ta=25°)

 Drain to gate voltage  $V_{DGO}$ 15 V Source to gate voltage V<sub>sgo</sub> 15 ٧ Drain current ĺρ 50 mΑ Gate current lG 5 mA Allowable power dissipation Рρ 150 mW Junction temperature Τi 150 .C Storage temperature Tstg -55 to +150.C

6.6 pF(Typ.)

2.9±0.2 38 1.2±0.2

0 ~ 0.1

0.4-0.05

1.9

1: Drain
2: Source
M-232 3: Gate

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Electrical Characteristics 市商

Unless otherwise specified (Ta = 25°C)

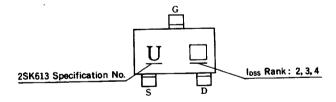
item	Symbol	Condition	Min.	Тур.	Max.	Unit
Drain to Gate Voltage	V <sub>DGO</sub>	$I_G = 10 \mu\text{A}$	15			٧
Source to Gate Voltage	Vsgo	I <sub>G</sub> = 10 μA	15			٧
Drain to Source Voltage	V <sub>DSX</sub>	$I_D = 10 \mu\text{A}, \ \ V_{GS} = +3 \text{V}$	15			٧
Gate Cutoff Current	Igss	$V_{GS} = -7 \text{ V}, V_{DS} = 0 \text{ V}$			-2	nA
Drain Current	loss *	V <sub>GS</sub> = 5 V, V <sub>GS</sub> = 0 V	13.4		42.0	mA
Gate to Source Cutoff Voltage	V <sub>GS(OFF)</sub> *	$V_{DS} = 5 \text{ V}, I_{D} = 100 \mu\text{A},$	-0.65		-2.0	٧
Forward Transfer Admittance	Y <sub>fs</sub>   *	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 0 V, f = 1 kHz	23	30		mS
Input Capacitance	Ciss	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 0 V, f = 1 MHz		6.6	7.5	pF
Equivalent Input Noise Voltage	- e <sub>n</sub>	$V_{DS}=5V,\ I_D=10\text{mA},\ Rg=0\Omega,$ f = 1 kHz		4.0	7.0	nV/√Hz

( \*Drain current detail specification as follows.)

#### Classification

	$I_{DSS}(mA)$ $\begin{cases} V_{DS} = 5 \text{ V} \\ V_{GS} = 0 \text{ V} \end{cases}$	$V_{GS(OFF)}(V) \left( \begin{array}{l} V_{DS} = 5 V \\ I_{D} = 100 \mu\text{A} \end{array} \right)$	$\mid Y_{fs} \mid (mS) \begin{pmatrix} V_{DS} = 5 \text{ V} \\ V_{GS} = 0 \text{ V} \\ f = 1 \text{ kHz} \end{pmatrix}$	Mark
2SK613-2	13.4 to 21.0	-0.65 to -1.26	23	2
2SK613-3	19.0 to 30.2	-0.85 to -1.6	25	3
2SK613-4	27.4 to 42.0	-1.05 to -2.0	29	4_

#### Mark



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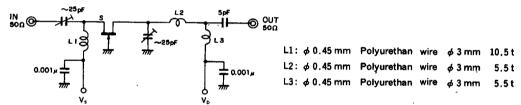
Standard Circuit Decign Date

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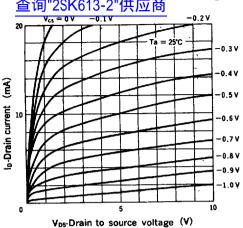
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Standard Circuit Design Data 量词 2SK613-2 共 図商				
Item	Symbol	Condition	Тур.	Unit
Forward Transfer Admittance	Y <sub>fs</sub>	$V_{DS} = 5 \text{ V}, I_{D} = 10 \text{ mA}, f = 1 \text{ kHz}$	-25	mS
Input Capacitance	Ciss	V <sub>DS</sub> = 5 V, I <sub>D</sub> = 10 mA, f = 1 MHz	5.5	pF
Gate Cutoff Current	la	V <sub>DG</sub> = 5 V, I <sub>D</sub> = 10 mA		pΑ
Input Resistance	ris	$V_{DS} = 5 \text{ V}, I_{D} = 10 \text{ mA}, f = 100 \text{ MHz}$	3,5	kΩ
Input Capacitance	C <sub>18</sub>		5.5	pF
Output Resistance	ros		2.0	kΩ
Output ,Capacitance	Cos		1.5	pF
Power Gain	PG			dB.
Noise Figure	NF	$V_{DS} = 5 \text{ V}, I_D = 10 \text{ mA}, f = 100 \text{ MHz}$	1.8	dB
Equivalent Input Noise Voltage	ēn	$V_{DS}=5V,\;I_{D}=10\text{mA,}\;f=1\text{kHz,}\;Rg=0\Omega$	4.0	nV/√Hz
Reverse Transfer	Crss	$V_{DS} = 5 \text{ V}, \ V_S = 0 \text{ V}, \ f = 1 \text{ MHz}$	1.6	pF

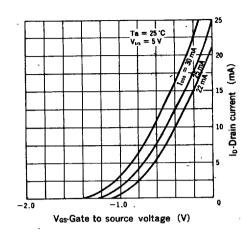
#### 100 MHz PG, NF Test Circuit



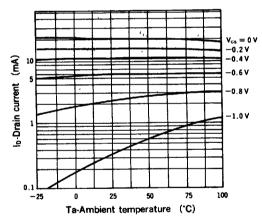




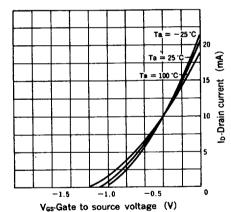
#### Drain current vs. Gate to source voltage



#### Drain current vs. Ambient temperature



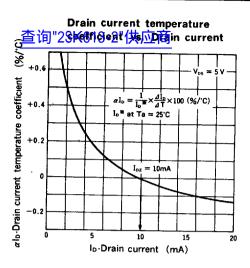
#### Drain current vs. Gate to source voltage

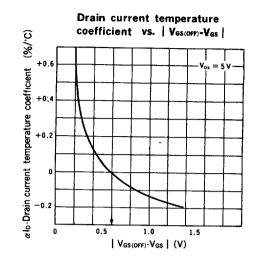


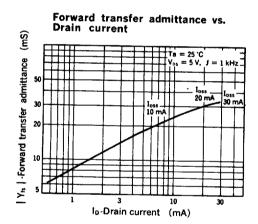




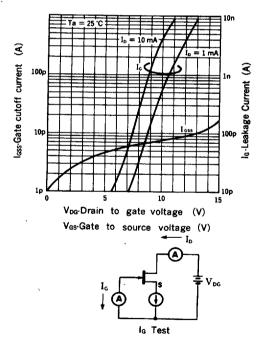


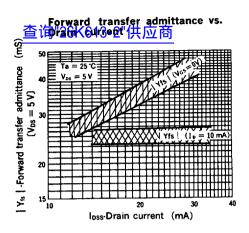




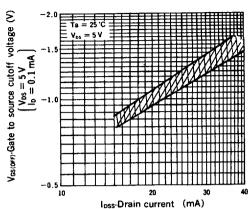




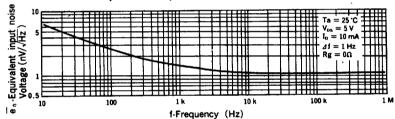




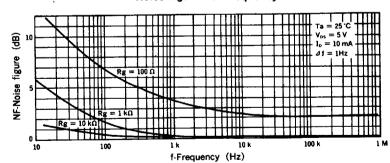
#### Gate to source cutoff voltage vs. Drain current



#### Equivalent input noise voltage vs. Frequency



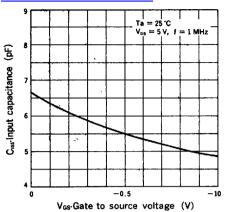
#### Noise figure vs. Frequency



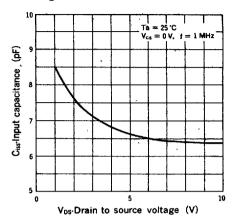
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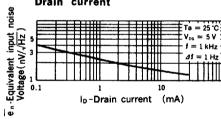




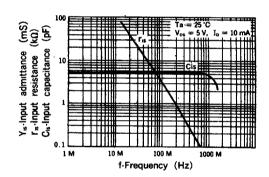
## Input capacitance vs. Drain to source voltage



## Equivalent input noise voltage vs. Drain current



#### Input admittance vs. Frequency







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